			1 00	m:
L Number	Hits		DB	Time stamp
-	468	[·	USPAT	2002/03/07 14:35
-	441	349/138	USPAT	2001/08/30 09:54
-	429	349/113	USPAT	2001/08/30 09:56
_	839	(passivation or dielectric) and (liquid adj	USPAT	2002/03/07 14:40
		crystal) and (change\$ with reflect\$) and		. ,
		thicks		
	56		USPAT	2001/08/30 10:44
-	36		USFAI	2001/08/30 10:44
		with reflect\$) and thick\$ and 349/113		
-	19	(passivation or dielectric) and (change\$	USPAT	2001/08/30 11:05
		with reflect\$) and thick\$ and 349/138		
-	18	(passivation or dielectric) and (change\$	USPAT	2001/08/30 11:15
		with reflect\$) and thick\$ and 349/122		
-	503	349/122	USPAT	2002/03/07 14:37
_	483	349/138	USPAT	2002/03/07 14:38
_	490	l '.	USPAT	2002/03/07 14:39
_	939		USPAT	2002/03/07 14:39
	616	· ·	USPAT	2002/03/07 14:39
-			i	
-	11044		USPAT	2002/03/07 14:41
		crystal)		
-	289		USPAT	2002/03/08 09:41
		(liquid adj crystal))		
-	214		USPAT	2002/03/07 14:43
		(liquid adj crystal))		
	496		USPAT	2002/03/07 14:43
	4,70	(liquid adj crystal))	331111	2002,00,0,14.45
	360	l 7	IICDAT	2002/03/07 14:43
-	369		USPAT	2002/03/0/ 14:43
		(liquid adj crystal))		0000/00/00 = = : :=
-	149		USPAT	2002/03/07 14:45
		crystal)) and (periphe\$4 adj region)		
-	369	(((passivation or dielectric) and (liquid	USPAT	2002/03/08 08:33
		adj crystal)) and (periphe\$4 adj circuit))		
		or (((passivation or dielectric) and (liquid		
		adj crystal)) and (periphe\$4 adj region))		
· .	217		USPAT	2002/03/07 17:45
-	21/		USFAI	2002/03/07 17.43
		(liquid adj crystal))		
-	220		USPAT	2002/03/07 16:30
-	488	1 '	USPAT	2002/03/07 17:30
-	313		USPAT	2002/03/07 17:47
		silicon) and (liquid adj crystal))		
-	706	((passivation or dielectric or	USPAT	2002/03/08 08:39
		silicon)and(liquid adj crystal)) and		
		((periphe\$4 adj circuit)or(periphe\$4 adj		
		region))		
	359	I = =	USPAT	2002/03/08 08:39
] -	339		USFAI	2002/03/00 00.39
		silicon) and (liquid adj crystal)) and		
		((periphe\$4 adj circuit)or(periphe\$4 adj		
		region)) and panel		
-	204	((passivation or dielectric or	USPAŢ	2002/03/08 08:40
		silicon)and(liquid adj crystal)) and		
		((periphe\$4 adj circuit)or(periphe\$4 adj		1
		region)) and panel and reflect\$6		
-	12	((passivation or dielectric) and (liquid adj	USPAT	2002/03/08 09:14
		crystal)) and (periphery adj circuit)		, , , , , , , , , , , , , , , , , , , ,
_	. 235	((passivation or dielectric) and (liquid adj	USPAT	2002/03/08 09:15
_	433		JULAI	2002/03/00 09:15
		crystal)) and (periphe\$4 adj circuit)	HODEM	2002/02/02 02 12
-	179	349/138 and (passivation or dielectric or	USPAT	2002/03/08 09:43
		silicon) and (edge or periphery)		
-	47	349/138 and (passivation or dielectric or	USPAT	2002/03/08 11:06
		silicon) and (edge or periphery)and seal		
-	41	349/43 and (passivation or dielectric or	USPAT	2002/03/08 10:05
		silicon) and (edge or periphery) and seal		
-	65		USPAT	2002/03/08 10:51
		silicon) and (edge or periphery) and seal		
_	22		USPAT	2002/03/08 11:06
[22	silicon) and (edge or periphery) and seal	332.71	
_	4.0		HCDAT	2002/02/09 11:07
-	46		USPAT	2002/03/08 11:07
1		silicon) and (edge or periphery) and seal		0000/05/55
-	58	349/149 and (passivation or dielectric or	USPAT	2002/03/08 11:08
]		silicon) and (edge or periphery)and seal		
-	1	5056895.pn.	USPAT	2004/01/14 15:52
<u>[- </u>	1	5978056.pn.	USPAT	2004/01/14 16:45
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- 1 6344888.pn. USPAT 2004/01/14 16:45